



# NCE N-Channel Enhancement Mode Power MOSFET

## Description

The NCE1520 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

## **General Features**

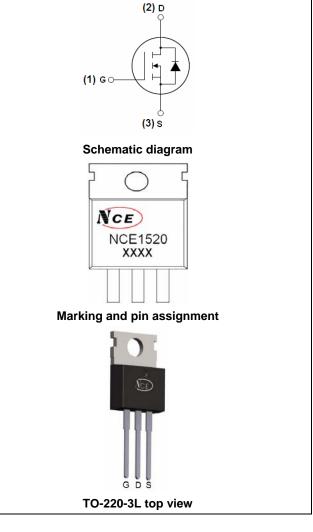
- $V_{DS} = 150V, I_D = 20A$   $R_{DS(ON)} < 80m\Omega @ V_{GS} = 10V$  (Typ:65m $\Omega$ )  $R_{DS(ON)} < 90m\Omega @ V_{GS} = 7V$  (Typ:70m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

## Application

- Boost converters
- LED backlighting
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE1520	NCE1520	TO-220-3L	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
Vds	Drain-Source Voltage	150	V
Vgs	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	20	А
I <sub>D</sub> (100℃)	Drain Current-Continuous(TC=100°C)	14	A
I <sub>DM</sub>	Pulsed Drain Current	40	A
P <sub>D</sub>	Maximum Power Dissipation	90	W
	Derating factor	0.6	W/℃
E <sub>AS</sub>	Single pulse avalanche energy (Note 5)	80	mJ
$T_{J},T_{STG}$	Operating Junction and Storage Temperature Range	-55 To 175	°C





## **Thermal Characteristic**

R <sub>θJC</sub>	Thermal Resistance, Junction-to-Case (Note 2)	1.7	°C/W
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## Electrical Characteristics (T<sub>c</sub>=25°C unless otherwise noted)

	Symbol Parameter	Condition	Min	Тур	Max	Unit
Off Characteris	stics		·			
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	150	165	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =150V,V <sub>GS</sub> =0V	-	-	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteris	tics <sup>(Note 3)</sup>		•			
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	2	3.4	4	V
R <sub>DS(ON)</sub>	Drain Course On State Desistance	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	65	80	mΩ
	Drain-Source On-State Resistance	V <sub>GS</sub> =7V, I <sub>D</sub> =10A	-	70	90	mΩ
<b>g</b> <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> =5V,I <sub>D</sub> =10A	-	20	-	S
Dynamic Chara	acteristics (Note4)		•			
C <sub>lss</sub>	Input Capacitance		-	1810	-	PF
C <sub>oss</sub>	Output Capacitance	- V <sub>DS</sub> =75V,V <sub>GS</sub> =0V, F=1.0MHz	-	61	-	PF
C <sub>rss</sub>	Reverse Transfer Capacitance	F=1.0MHZ	-	45	-	PF
Switching Char	racteristics (Note 4)		•			
t <sub>d(on)</sub>	Turn-on Delay Time		-	15.5	-	nS
tr	Turn-on Rise Time		-	8.5	-	nS
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ =10V, $R_{GEN}$ =3 $\Omega$	-	19.5	-	nS
t <sub>f</sub>	Turn-Off Fall Time		-	7	-	nS
Qg	Total Gate Charge		-	45	-	nC
Q <sub>gs</sub>	Gate-Source Charge	- V <sub>DS</sub> =75V,I <sub>D</sub> =10A,	-	9	-	nC
Q <sub>gd</sub>	Gate-Drain Charge	- V <sub>GS</sub> =10V	-	12	-	nC
Drain-Source D	Diode Characteristics					
V <sub>SD</sub>	Diode Forward Voltage (Note 3)	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Is	Diode Forward Current (Note 2)	-	-	-	20	A
t <sub>rr</sub>	Reverse Recovery Time	TJ = 25°C, IF = 10A	-	32	-	nS
Qrr	Reverse Recovery Charge	di/dt = 100A/µs <sup>(Note3)</sup>	-	53	-	nC
t <sub>on</sub>	Forward Turn-On Time	Intrinsic turn-on time is negl	igible (turr	n-on is do	minated b	y LS+LD)
		•				

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

- 3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition:Tj=25 $^\circ \!\! \mathbb{C}$ ,V\_{DD}=50V,V\_G=10V,L=0.5mH,Rg=25\Omega

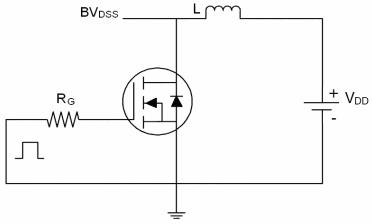


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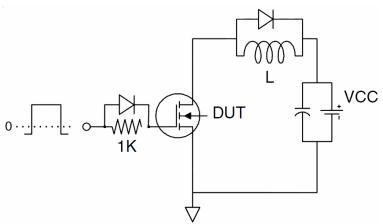
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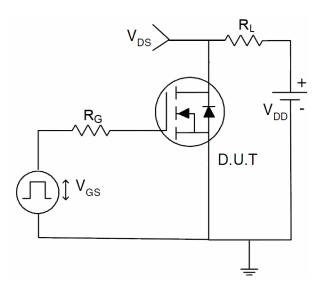
## Test Circuit 1) E<sub>AS</sub> Test Circuit



## 2) Gate Charge Test Circuit



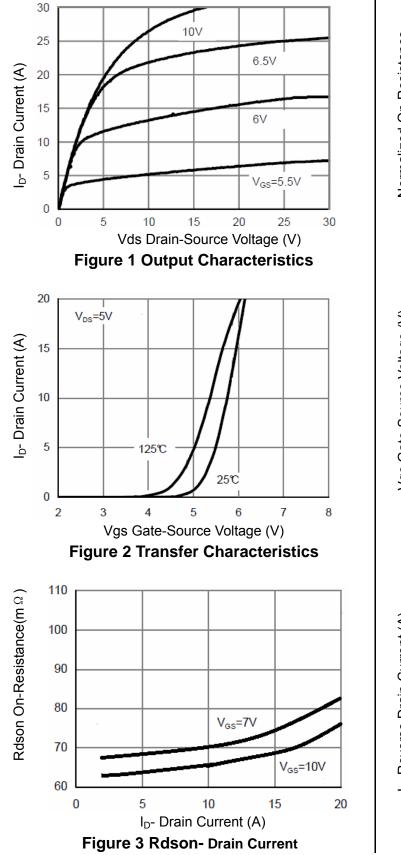
3) Switch Time Test Circuit

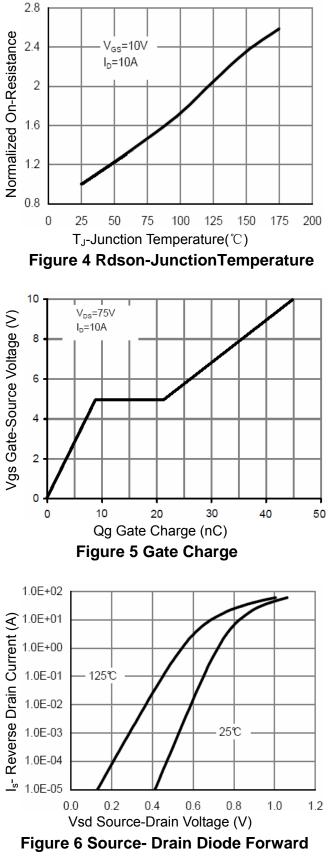






## **Typical Electrical and Thermal Characteristics (Curves)**



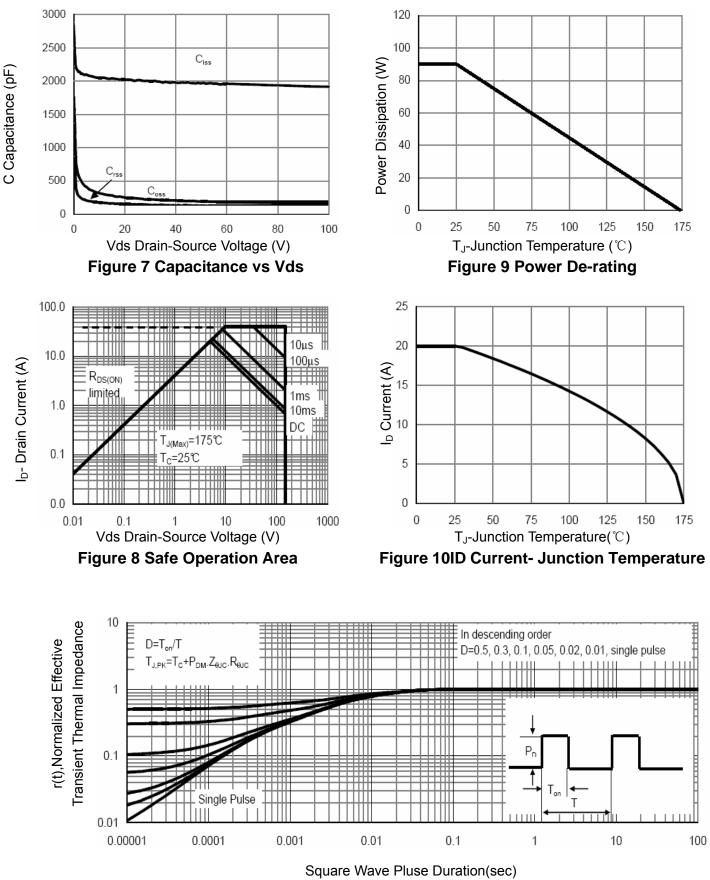




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NCE1520





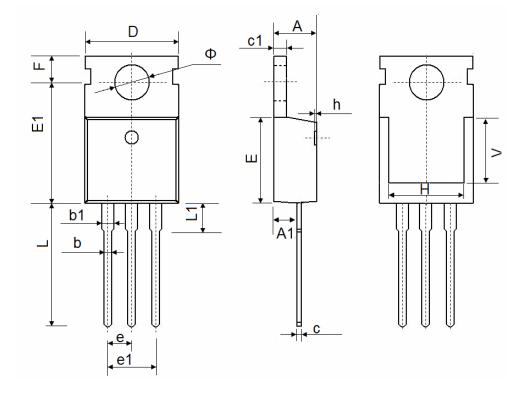


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# TO-220-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Φ	3.400	3.800	0.134	0.150	







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